Vishay Semiconductors

# High Performance Schottky Rectifier, 100 A





PowerTab<sup>®</sup>

PRODUCT SUMMARY				
Package	PowerTab <sup>®</sup>			
I <sub>F(AV)</sub>	100 A			
V <sub>R</sub>	30 V			
V <sub>F</sub> at I <sub>F</sub>	0.56 V			
I <sub>RM</sub>	460 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			
E <sub>AS</sub>	9 mJ			

www.vishay.com

### FEATURES

- 150 °C max. operating junction temperature
- High frequency operation
- Ultralow forward voltage drop
- Continuous high current operation
- Guard ring for enhanced ruggedness and long term reliability
   COMPLIANT
   COMPLIANT
- Screw mounting only
- AEC-Q101 qualified
- PowerTab<sup>®</sup> package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The VS-100BGQ030HF4 Schottky rectifier has been optimized for ultralow forward voltage drop specifically for low voltage output in high current AC/DC power supplies. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I	Rectangular waveform	100	А			
I <sub>F(AV)</sub>	T <sub>C</sub>	106	°C			
V <sub>RRM</sub>		30	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	4500	А			
M	100 A <sub>pk</sub> (typical)	0.49	V			
V <sub>F</sub>	TJ	150	°C			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-100BGQ030HF4	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	30	V		
Maximum working peak reverse voltage	num working peak reverse voltage V <sub>RWM</sub>		v		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 106 °C	100	А		
Maximum peak one cycle non-repetitive surge current	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	4500	A	
		10 ms sine or 6 ms rect. pulse	$V_{\text{RRM}}$ applied	850		
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 8 A, L = 1.12 mH 36		36	mJ	
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical 8		А		

 Revision: 15-Jun-15
 1
 Document Number: 93802

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 DiodesEurope@vishay.com

 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI
 Downloaded From Oneyac.com
 w.vishay.com/doc?91000





## **Vishay Semiconductors**

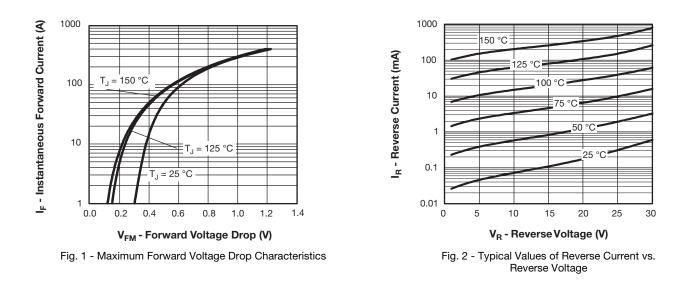
TRICAL	OBEA	
- I KI(-AI	SPEC	IONS

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	TYP.	MAX.	UNITS	
		50 A	T <sub>.1</sub> = 25 °C	0.47	0.5	v
Forward valtage drap	V <sub>FM</sub> <sup>(1)</sup>	100 A	1j=25 C	0.56	0.63	
Forward voltage drop	VFM (')	50 A	T 150 %C	0.36	0.4	
		100 A	T <sub>J</sub> = 150 °C	0.49	0.56	
		T <sub>J</sub> = 125 °C, V <sub>R</sub> = 15 V		80	160	
	I <sub>BM</sub> <sup>(1)</sup>	$T_{J} = 150 \text{ °C}, V_{R} = 30 \text{ V}$		800	1100	
Reverse leakage current	IRM (")	T <sub>J</sub> = 25 °C		0.6	2.4	mA
		T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	260	460	
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ , (test signal range 100 kHz to 1 MHz) 25 °C 38			00	pF
Typical series inductance	L <sub>S</sub>	Measured from tab to mounting plane 3.5 nl			nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V/µs			V/µs	

#### Note

<sup>(1)</sup> Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	PARAMETER SYMBOL TEST CONDITIONS		TEST CONDITIONS	VALUES	UNITS	
Maximum junction and temperature range	storage	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C	
Maximum thermal resis junction to case	tance,	R <sub>thJC</sub> DC operation		0.50	°C/W	
Typical thermal resistar case to heatsink	nce,	R <sub>thCS</sub> Mounting surface, smooth and greased		0.30	0,00	
A				5	g	
Approximate weight	Approximate weight			0.18	oz.	
minimum				1.2 (10)	N · m	
Mounting torque maxi	maximum			2.4 (20)	(lbf · in)	
Marking device         Case style PowerTab <sup>®</sup> 100BG		Q030H				



Revision: 15-Jun-15

2

Document Number: 93802

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From Oneyac.com

## VS-100BGQ030HF4

**Vishay Semiconductors** 



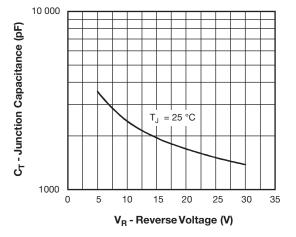


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

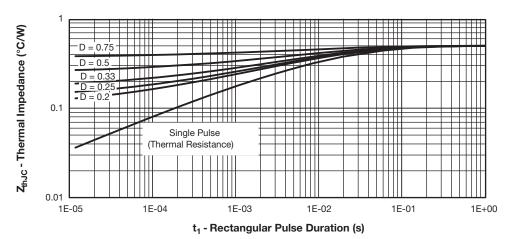
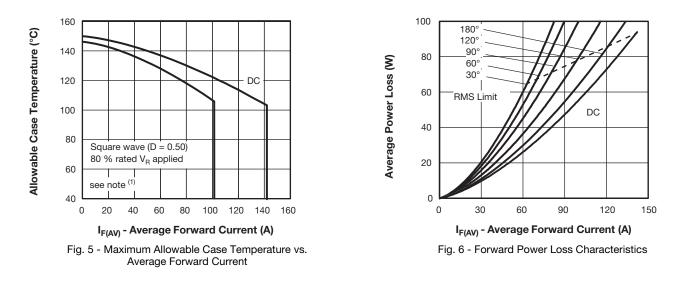


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



Revision: 15-Jun-15

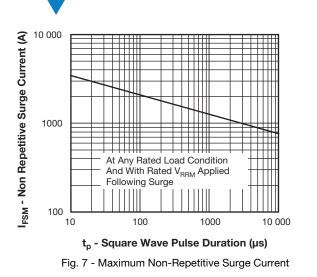
3

Document Number: 93802

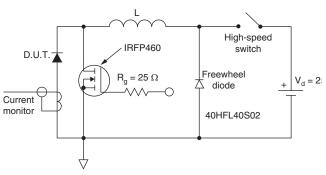
For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From Oneyac.com

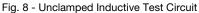
# VS-100BGQ030HF4

## **Vishay Semiconductors**



www.vishay.com





### Note

 $^{(1)}$  Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \ x \ R_{thJC};$ Pd = Forward power loss =  $I_{F(AV)} \ x \ V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6); Pd\_{REV} = Inverse power loss =  $V_{R1} \ x \ I_R \ (1 - D); \ I_R \ at \ V_{R1} = 80 \ \%$  rated  $V_R$ 

### **ORDERING INFORMATION TABLE**

Device code	VS-	100	BGQ	030	н	F4	
		(2)	(3)	(4)	(5)	(6)	I
		- Visl	hay Sem	niconduc	tors pro	oduct	
	2	- Cur	rent rati	ng (100	= 100 A	<b>(</b> )	
	3	- Ess	sential pa	art numt	ber		
	4	- Vol	tage rati	ng (030	= 30 V)		
	5	- H=	AEC-Q	101 qua	lified		
	6	- Env	/ironmer	ntal digit	:		
		- F4	= RoHS	complia	int and t	otally le	ad (Pb)-fre

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-100BGQ030HF4	25	375	Antistatic plastic tube			

#### LINKS TO RELATED DOCUMENTS

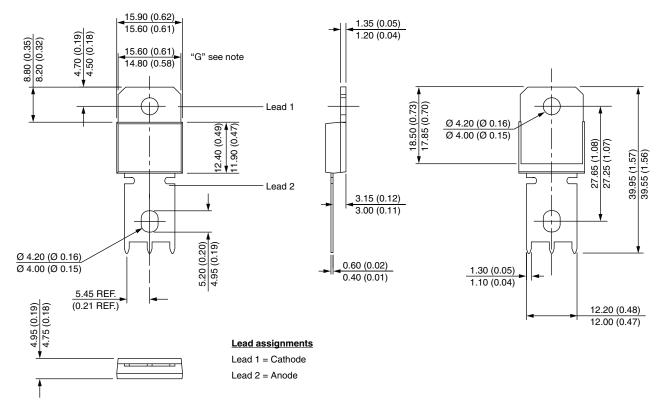
Dimensions	www.vishay.com/doc?95240
Part marking information	www.vishay.com/doc?95467
Application note	www.vishay.com/doc?95179



Vishay Semiconductors

**PowerTab**<sup>®</sup>

### **DIMENSIONS** in millimeters (inches)



Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)